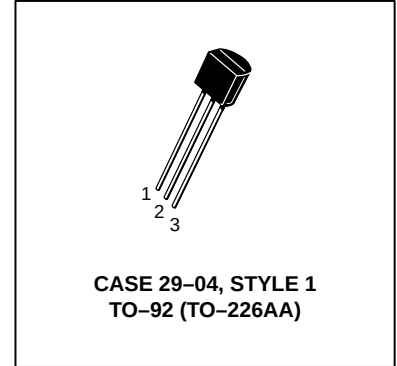
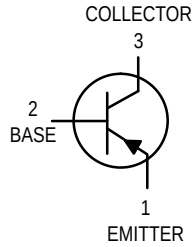



MAXIMUM RATINGS

Rating	Symbol	MPSA92	MPSA93	Unit
Collector–Emitter Voltage	V_{CEO}	–300	–200	Vdc
Collector–Base Voltage	V_{CBO}	–300	–200	Vdc
Emitter–Base Voltage	V_{EBO}	–5.0		Vdc
Collector Current — Continuous	I_C	–500		mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0		mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12		Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C/W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ⁽¹⁾ ($I_C = -1.0 \text{ mAdc}$, $I_E = 0$)	MPSA92 MPSA93	$V_{(BR)CEO}$	–300 –200	— —	Vdc
Collector–Base Breakdown Voltage ($I_C = -100 \mu\text{Adc}$, $I_E = 0$)	MPSA92 MPSA93	$V_{(BR)CBO}$	–300 –200	— —	Vdc
Emitter–Base Breakdown Voltage ($I_E = -100 \mu\text{Adc}$, $I_C = 0$)		$V_{(BR)EBO}$	–5.0	—	Vdc
Collector Cutoff Current ($V_{CB} = -200 \text{ Vdc}$, $I_E = 0$) ($V_{CB} = -160 \text{ Vdc}$, $I_E = 0$)	MPSA92 MPSA93	I_{CBO}	— —	–0.25 –0.25	μAdc
Emitter Cutoff Current ($V_{EB} = -3.0 \text{ Vdc}$, $I_C = 0$)		I_{EBO}	—	–0.1	μAdc

1. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS(1)				
DC Current Gain ($I_C = -1.0\text{ mA}$, $V_{CE} = -10\text{ Vdc}$) ($I_C = -10\text{ mA}$, $V_{CE} = -10\text{ Vdc}$)	Both Types Both Types	25 40	— —	—
($I_C = -30\text{ mA}$, $V_{CE} = -10\text{ Vdc}$)	MPSA92 MPSA93	25 25	— —	—
Collector-Emitter Saturation Voltage ($I_C = -20\text{ mA}$, $I_B = -2.0\text{ mA}$)	MPSA92 MPSA93	— —	-0.5-0 .4	Vdc
Base-Emitter Saturation Voltage ($I_C = -20\text{ mA}$, $I_B = -2.0\text{ mA}$)		—	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current-Gain — Bandwidth Product ($I_C = -10\text{ mA}$, $V_{CE} = -20\text{ Vdc}$, $f = 100\text{ MHz}$)		50	—	MHz
Collector-Base Capacitance ($V_{CB} = -20\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	MPSA92 MPSA93	— —	6.08. 0	pF

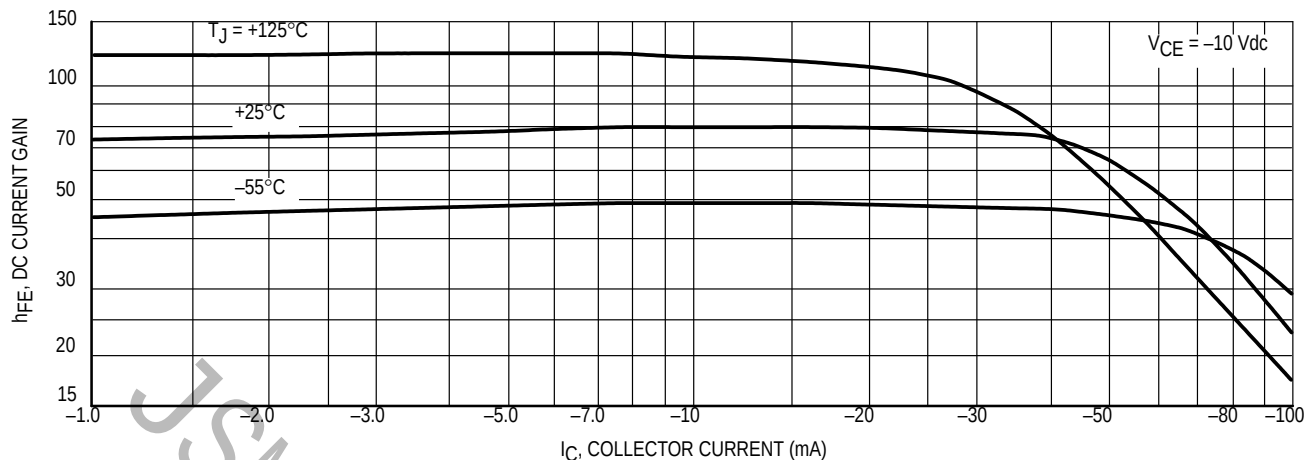


Figure 1. DC Current Gain

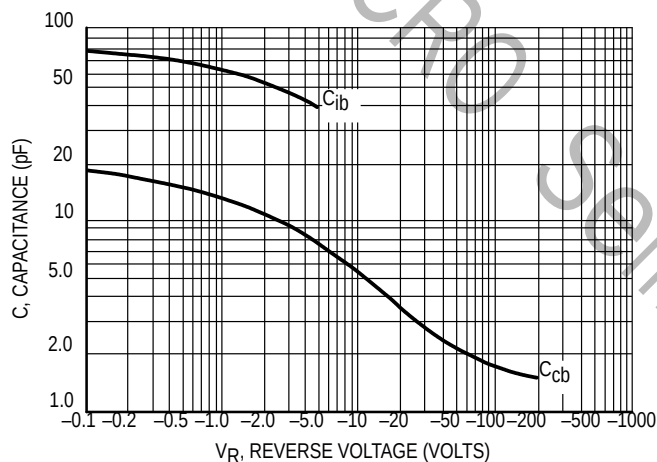


Figure 2. Capacitances

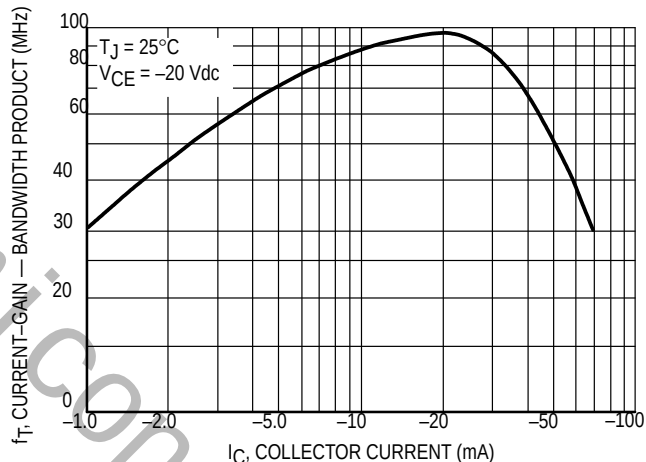


Figure 3. Current-Gain — Bandwidth Product

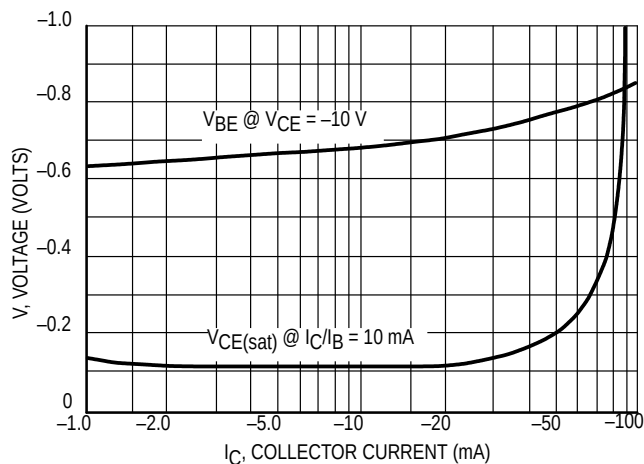


Figure 4. "On" Voltages

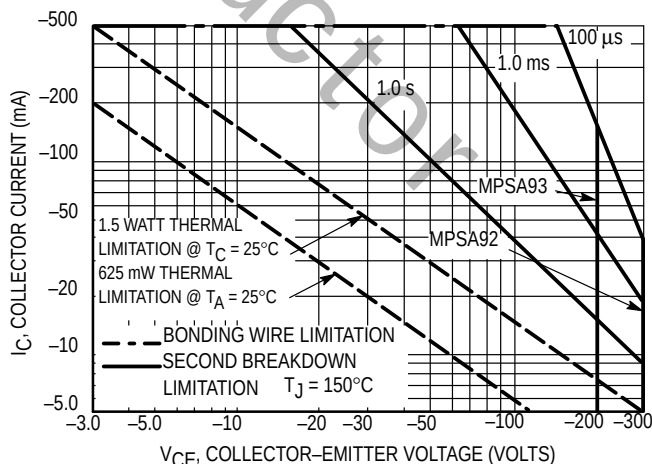
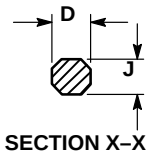
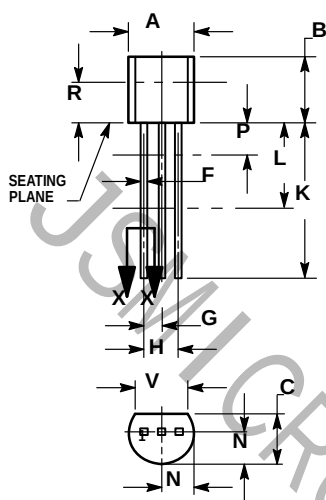


Figure 5. Active Region — Safe Operating Area

PACKAGE DIMENSIONS



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
AB	0.175	0.205	4.45	5.20
CD	0.170	0.210	4.32	5.33
F	0.125	0.165	3.18	4.19
	0.016	0.022	0.41	0.55
	0.016	0.019	0.41	0.48
GH	0.045	0.055	1.15	1.39
JK	0.095	0.105	2.42	2.66
LN	0.015	0.020	0.39	0.50
PR	0.500	—	12.70	—
V	0.250	—	6.35	—
	0.080	0.105	2.04	2.66
	—	0.100	—	2.54
	0.115	—	2.93	—
	0.135	—	3.43	—

STYLE 1:
 PIN 1. EMITTER
 2. BASE
 3. COLLECTOR